

**Product data sheet** 

### **1. General description**

Planar passivated Silicon Controlled Rectifier in a TO247 plastic package intended for use in applications requiring very high inrush current capability and high thermal cycling performance.

### 2. Features and benefits

- High thermal cycling performance
- · Planar passivated for voltage ruggedness and reliability
- High voltage capacity
- · Very high current surge capability

## **3. Applications**

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control
- Uninterruptible Power Supply (UPS)
- Solid State Relay (SSR)
- Traction battery charging

### 4. Quick reference data

Table 1. Quick reference data							
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Absolute maximum rating							
$V_{\text{DRM}}$	repetitive peak off-state voltage			-	-	1400	V
$V_{\text{RRM}}$	repetitive peak reverse voltage			-	-	1400	V
$I_{T(RMS)}$	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 129 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>		-	-	79	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig. 4; Fig. 5		-	-	650	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms		-	-	715	А
T <sub>j</sub>	junction temperature			-	-	150	°C

SCR

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static characteristics							
I <sub>GT</sub>	gate trigger current	$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; Fig. 7; Fig. 8		-	-	50	mA
Dynamic	Dynamic characteristics						
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{\text{DM}}$ = 938 V; $T_{j}$ = 125 °C; Gate open circuit; ( $V_{\text{DM}}$ = 67% of $V_{\text{DRM}}$ ); exponential waveform		1500	-	-	V/µs

### 5. Pinning information . .

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode		
2	A	anode		А <del>  </del> К G
3	G	gate		sym037
mb	A	mounting base; connected to anode		

# 6. Ordering information

Table 3. Ordering information								
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
TYN50W-1400T	TO247	TYN50W-1400TQ	Tube	30	TO247E	18-Jun-2021		

## 7. Marking

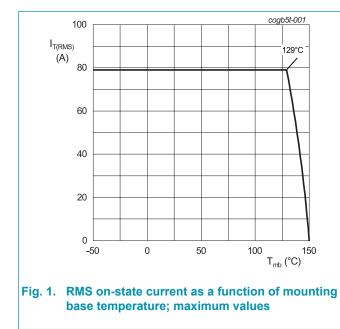
Table 4. Marking codes	
Type number	Marking codes
TYN50W-1400T	TYN50W 1400T

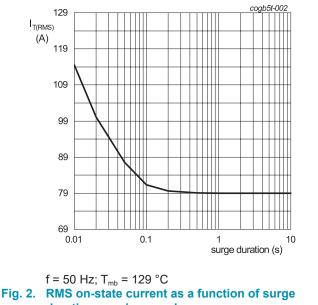
# 8. Limiting values

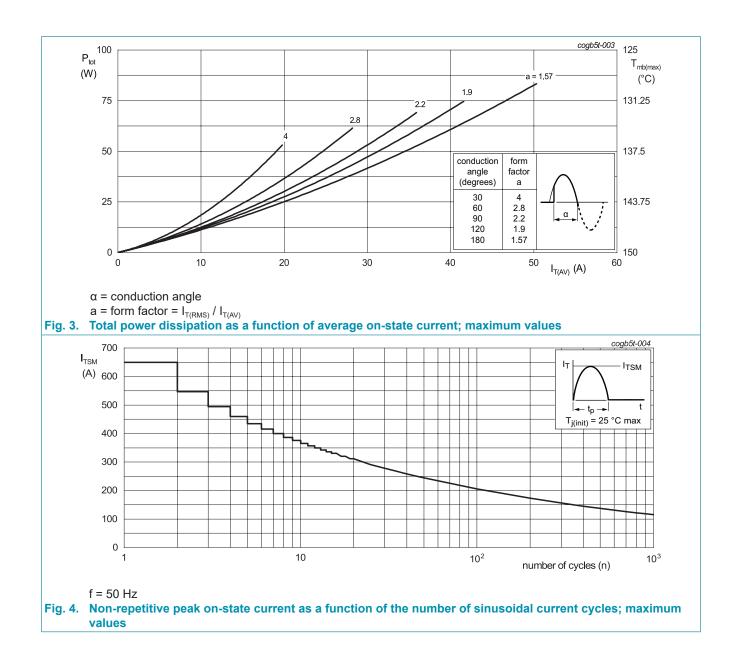
### Table 5. Limiting values

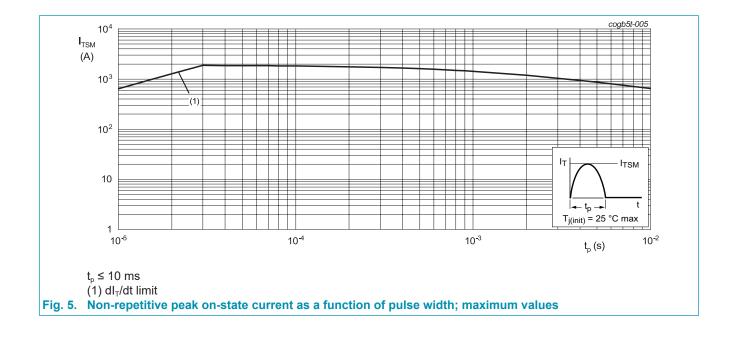
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage		-	1400	V
$V_{\text{RRM}}$	repetitive peak reverse voltage		-	1400	V
$I_{T(AV)}$	average on-state current	half sine wave; T <sub>mb</sub> ≤ 129 °C	-	50	А
$\mathbf{I}_{\mathrm{T}(\mathrm{RMS})}$	RMS on-state current	half sine wave; T <sub>mb</sub> ≤ 129 °C; <u>Fig 1; Fig 2; Fig 3</u>	-	79	A
I <sub>TSM</sub>	non-repetitive peak on- state current	half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 10 ms; Fig 4; Fig 5	-	650	A
		half sine wave; $T_{j(init)}$ = 25 °C; $t_p$ = 8.3 ms	-	715	А
l <sup>2</sup> t	l <sup>2</sup> t for fusing	t <sub>p</sub> = 10 ms; sine-wave pulse	-	2113	A <sup>2</sup> s
dl <sub>⊤</sub> /dt	rate of rise of on-state current	I <sub>G</sub> = 200mA	-	200	A/µs
I <sub>GM</sub>	peak gate current		-	8	А
$V_{\text{RGM}}$	peak reverse gate voltage		-	5	V
$P_{GM}$	peak gate power		-	20	W
$P_{G(AV)}$	average gate power	over any 20 ms period	-	1	W
T <sub>stg</sub>	storage temperature		-40	150	°C
T <sub>j</sub>	junction temperature		-	150	°C







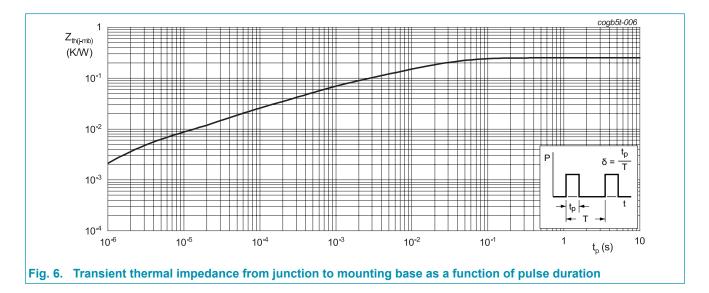


## 9. Thermal & Mechanical characteristics

### Table 6. Thermal & Mechanical characteristics

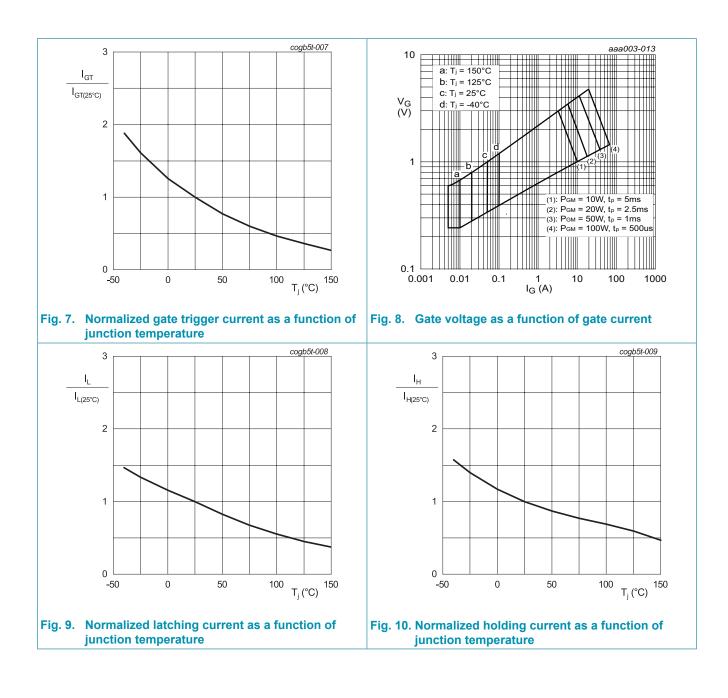
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to mounting base	<u>Fig 6</u>	-	-	0.25	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	50	-	K/W
	Mounting torque	M3 screw mounting	0.55	-	0.8	Nm

Note: It is recommended that a metal washer is inserted between screw head and mounting tab. Do not use self-tapping screws.

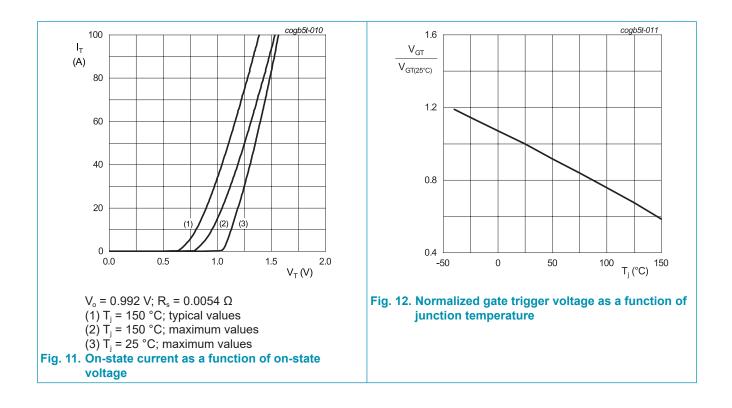


# **10. Characteristics**

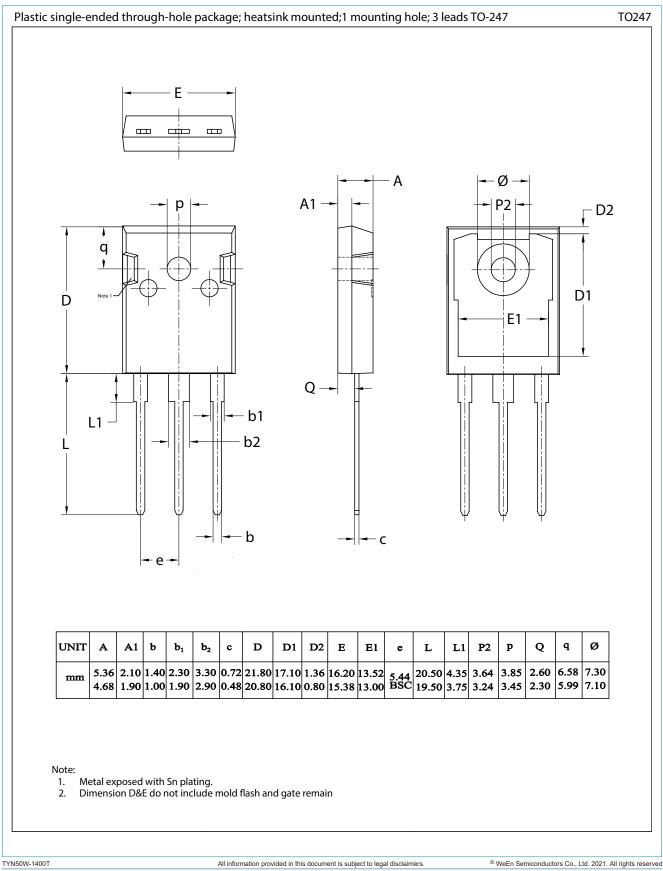
Table 7. Cl		Conditions	B.G.L.	True	Mary	1 lm 14
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics					
I <sub>GT</sub>	gate trigger current	$V_D = 12 V; I_T = 0.1 A; T_j = 25 °C;$ Fig. 7; Fig. 8	-	-	50	mA
IL	latching current	V <sub>D</sub> = 12 V; I <sub>G</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	300	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	-	200	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 50 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	-	1.35	V
		I <sub>T</sub> = 79 A; T <sub>j</sub> = 25 °C; <u>Fig. 11</u>	-	-	1.5	V
V <sub>GT</sub> gate trigger volta	gate trigger voltage	$V_{\rm D}$ = 12 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 25 °C; <u>Fig. 12</u>	-	0.7	1	V
		V <sub>D</sub> = 800 V; I <sub>T</sub> = 0.1 A; T <sub>j</sub> = 125 °C	0.25	0.4	-	V
I <sub>D</sub>	off-state current	V <sub>D</sub> = 1400 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>D</sub> = 1400 V; T <sub>j</sub> = 150 °C	-	-	10	mA
I <sub>R</sub> reverse curr	reverse current	V <sub>D</sub> = 1400 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>D</sub> = 1400 V; T <sub>j</sub> = 150 °C	-	-	10	mA
Dynamic	characteristics		·			
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 938 V; T <sub>j</sub> = 125 °C; Gate open circuit; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform	1500	-	-	V/µs
		$V_{DM}$ = 938 V; T <sub>j</sub> = 150 °C; Gate open circuit; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform	1000	-	-	V/µs
t <sub>gt</sub>	gate-controlled turn-on time	$ I_{TM} = 40 \text{ A};  \text{V}_{\text{D}} = 800  \text{V};  \text{I}_{\text{G}} = 0.1  \text{A};  \text{d} \text{I}_{\text{G}} \text{/} \\ \text{d} \text{t} = 5  \text{A} / \mu \text{s};  \text{T}_{\text{j}} = 25 ^{\circ}\text{C} $	-	2	-	μs
t <sub>q</sub>	commutated turn-off time		-	150	-	μs



### **WeEn Semiconductors**



## **11. Package outline**



# 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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